

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number: VFT2045CBP-M3/4W
Manufacturer: Vishay General Semiconductor - Diodes Division
Package: Tube
Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/vishay-general-semiconductor-diodes-division/vft2045cbp-m3-4w.html>



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Email: info@antrexco.com

WhatsApp: +86-186-8066-5326

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New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

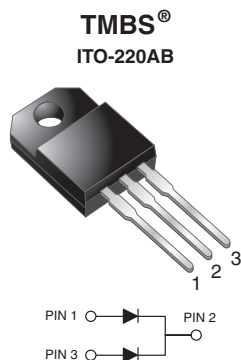
Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 5.0 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	45 V
I_{FSM}	160 A
V_F at $I_F = 10 \text{ A}$	0.41 V
T_{OP} max. (AC mode)	150 °C
T_J max. (DC forward current)	200 °C
Package	ITO-220AB
Circuit configuration	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VFT2045CBP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$ ⁽¹⁾	20	A
		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	160	A
Isolation voltage from terminal to heatsink, $t = 1 \text{ min}$	V_{AC}	1500	V
Operating junction and storage temperature range (AC mode)	T_{OP}, T_{STG}	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \leq 1 \text{ h}$	T_J ⁽²⁾	≤ 200	°C

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V
	I _F = 10 A			0.49	0.58	
	I _F = 5 A	T _A = 125 °C		0.33	-	
	I _F = 10 A			0.41	0.52	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	2000	μA
		T _A = 125 °C		10	30	mA

Notes

⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width $\leq 40 \text{ ms}$



THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	VFT2045CBP	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	6.0	$^{\circ}\text{C/W}$
	per device		4.5	

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT2045CBP-M3/4W	1.76	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

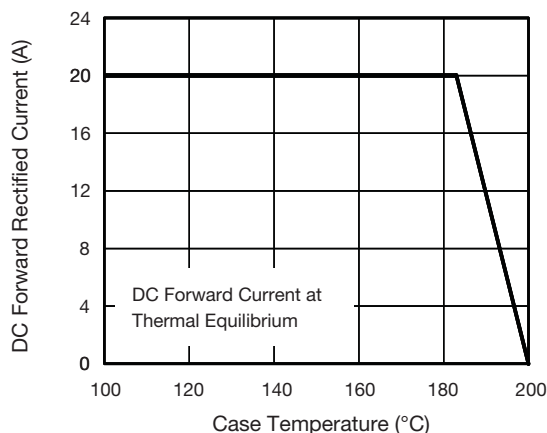


Fig. 1 - Maximum Forward Current Derating Curve

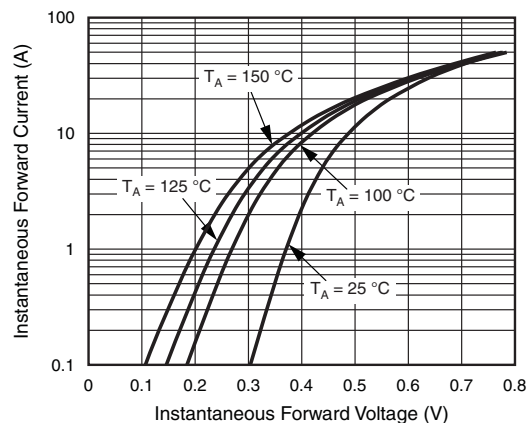


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

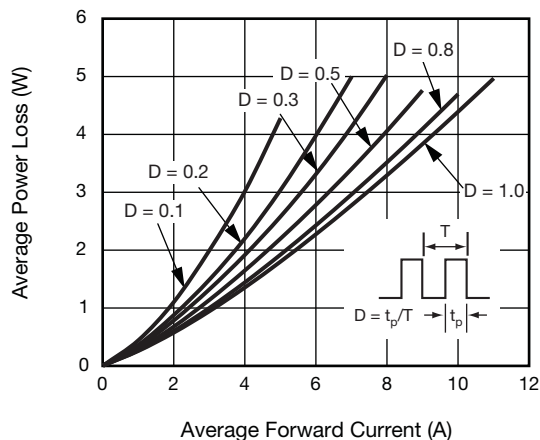


Fig. 2 - Forward Power Loss Characteristics Per Diode

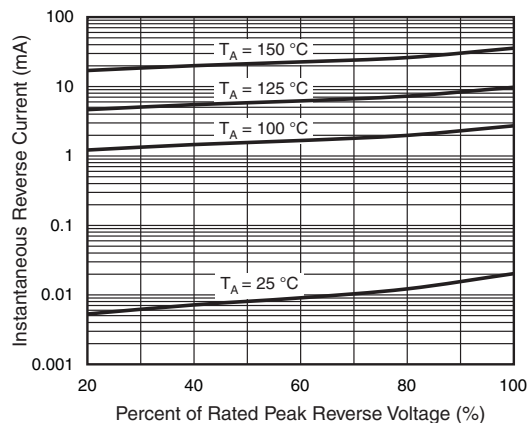


Fig. 4 - Typical Reverse Characteristics Per Diode

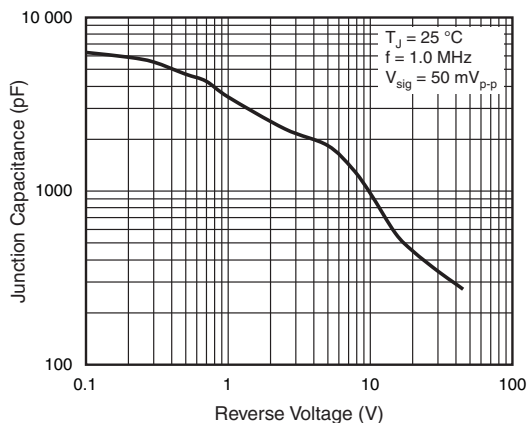


Fig. 5 - Typical Junction Capacitance Per Diode

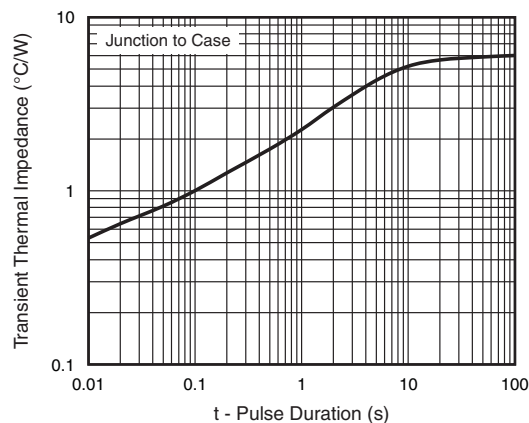
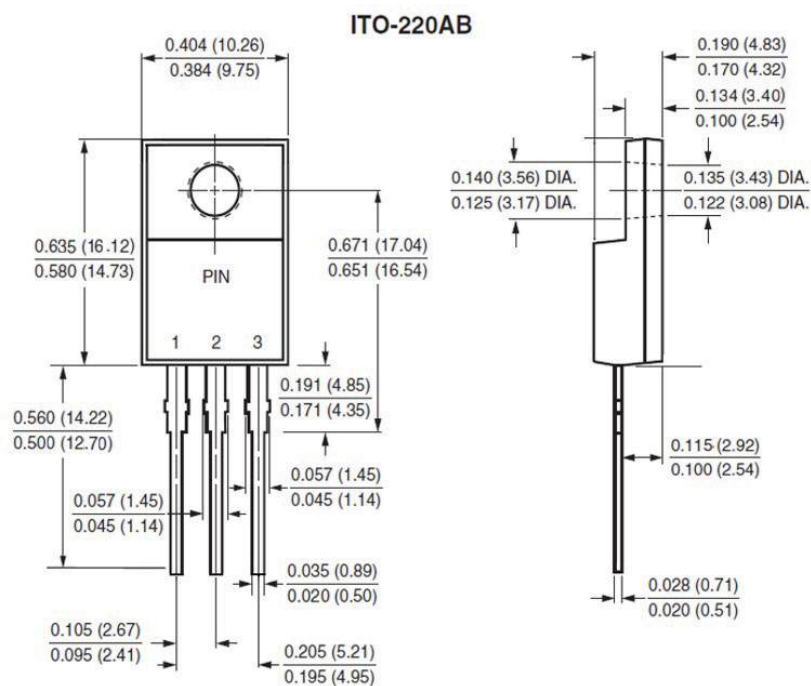


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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